March 2009



SEMICONDUCTOR

# FGH40N60SF 600V, 40A Field Stop IGBT

### Features

- High current capability
- Low saturation voltage: V<sub>CE(sat)</sub> =2.3V @ I<sub>C</sub> = 40A
- High input impedance
- Fast switching
- · RoHS compliant

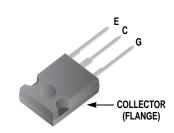
### **Applications**

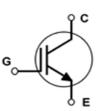
• Inverter, UPS, SMPS, PFC



# **General Description**

Using Novel Field Stop IGBT Technology, Fairchild's new sesries of Field Stop IGBTs offer the optimum performance for Inverter, UPS, SMPS and PFC applications where low conduction and switching losses are essential.





## **Absolute Maximum Ratings**

Symbol	Description		Ratings	Units	
V <sub>CES</sub>	Collector to Emitter Voltage		600	V	
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V	
Ι <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	80	A	
	Collector Current	@ T <sub>C</sub> = 100°C	40	A	
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	120	А	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	290	W	
	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	116	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

# **Thermal Characteristics**

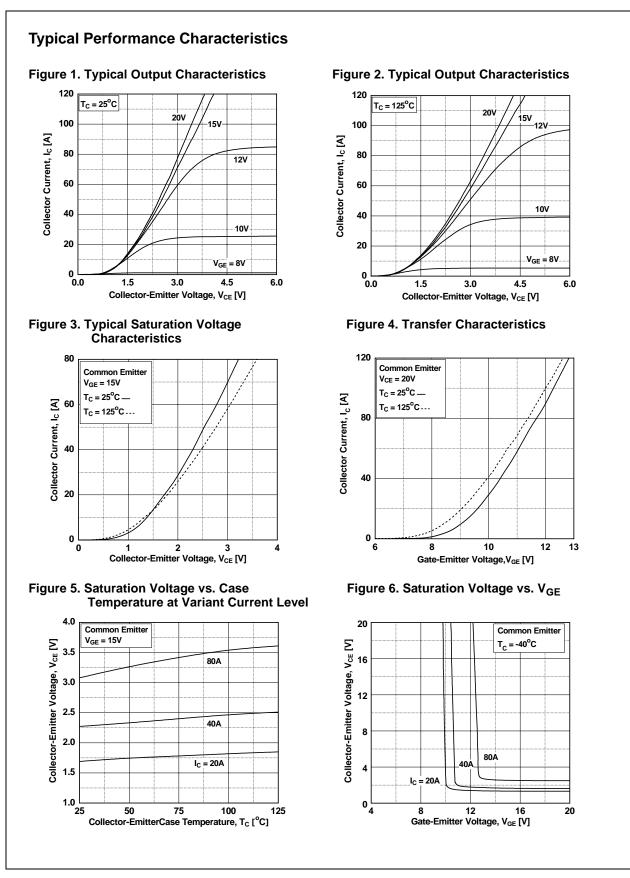
Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.43	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

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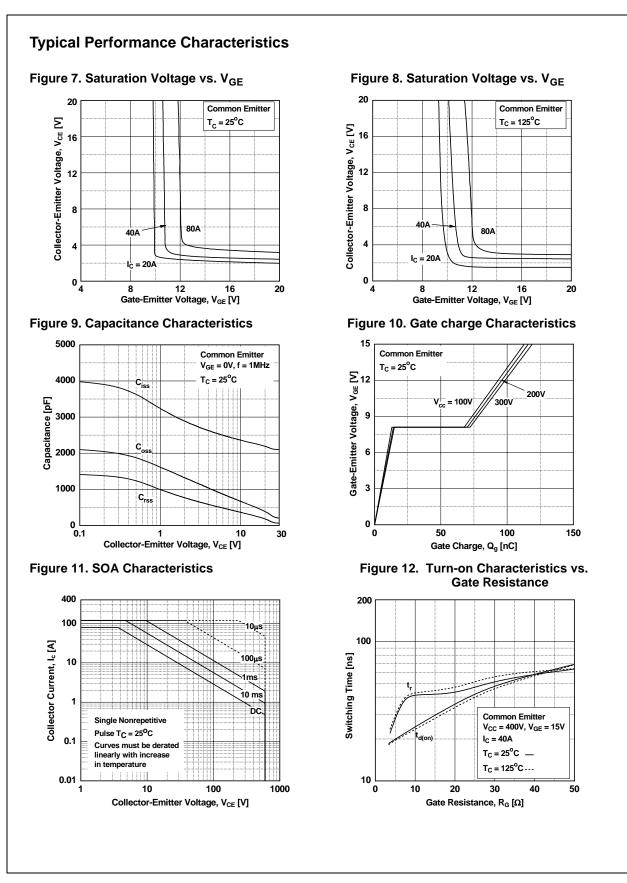
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Device Marking		Device F	Package	Packaging ackage Type	Qty per Tube		Max Qty per Box		
FGH40	N60SF	FGH40N60SFTU	TO-247	TO-247 Tube		30ea		-	
				1	1		L		
Electric	al Chai	racteristics of the		5°C unless otherwise noted					
Symbol		Parameter	Test	Conditions	Min.	Тур.	Max.	Units	
Off Charac	teristics								
BV <sub>CES</sub>	Collector	to Emitter Breakdown Voltage	e V <sub>GE</sub> = 0V, I <sub>C</sub>	= 250μA	600	-	-	V	
$\Delta BV_{CES}$ $\Delta T_J$		ure Coefficient of Breakdown			-	0.6	-	V/ºC	
I <sub>CES</sub>		Cut-Off Current	$V_{CE} = V_{CES}$	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0V		-	250	μA	
I <sub>GES</sub>	G-E Leak	age Current	$V_{GE} = V_{GES}$		-	-	±400	nA	
	· · ·		01 010		-			l	
On Charac	1	shold Voltage	I <sub>C</sub> = 250μA,	Ver - Ver	4.0	5.0	6.5	V	
V <sub>GE(th)</sub>	G-E Threshold Voltage Collector to Emitter Saturation Voltage		I <sub>C</sub> = 250μA, I <sub>C</sub> = 40A, V <sub>G</sub>		4.0	2.3	2.9	V	
V <sub>CE(sat)</sub>					_	2.5	-	V	
Dynamic C	haracteris	tics			1	1		1	
C <sub>ies</sub>	Input Cap	acitance		V <sub>CE</sub> = 30V, V <sub>GE</sub> = 0V, f = 1MHz		2110	-	pF	
C <sub>oes</sub>	Output Ca	apacitance				200	-	pF	
C <sub>res</sub>	Reverse -	Transfer Capacitance	1 - 111112			60	-	pF	
Switching	Characteri	stics							
t <sub>d(on)</sub>	Turn-On [	Delay Time			-	25	-	ns	
t <sub>r</sub>	Rise Time	)	_	-		42	-	ns	
t <sub>d(off)</sub>	Turn-Off	Delay Time	V <sub>CC</sub> = 400V,	I <sub>C</sub> = 40A,	-	115	-	ns	
t <sub>f</sub>	Fall Time		R <sub>G</sub> = 10Ω, V	′ <sub>GE</sub> = 15V,	-	27	54	ns	
Eon	Turn-On S	Switching Loss	Inductive Lo	ad, $T_{C} = 25^{\circ}C$	-	1.13	-	mJ	
E <sub>off</sub>	Turn-Off S	Switching Loss			-	0.31	-	mJ	
E <sub>ts</sub>	Total Swit	ching Loss		-		1.44	-	mJ	
t <sub>d(on)</sub>	Turn-On [	Delay Time			-	24	-	ns	
t <sub>r</sub>	Rise Time	9			-	43	-	ns	
t <sub>d(off)</sub>	Turn-Off [	Delay Time	V <sub>CC</sub> = 400V,	I <sub>C</sub> = 40A,	-	120	-	ns	
t <sub>f</sub>	Fall Time		R <sub>G</sub> = 10Ω, V	$R_G = 10\Omega$ , $V_{GE} = 15V$ , Inductive Load, $T_C = 125^{\circ}C$	-	30	-	ns	
E <sub>on</sub>	Turn-On S	Switching Loss	Inductive Lo		-	1.14	-	mJ	
E <sub>off</sub>	Turn-Off S	Switching Loss			-	0.48	-	mJ	
E <sub>ts</sub>	Total Swit	ching Loss			-	1.62	-	mJ	
Qg	Total Gate	e Charge			-	120	-	nC	
Q <sub>ge</sub>	Gate to E	mitter Charge	$V_{CE} = 400V,$	I <sub>C</sub> = 40A,	-	14	-	nC	
Q <sub>gc</sub>		ollector Charge	– V <sub>GE</sub> = 15V		-	58	-	nC	

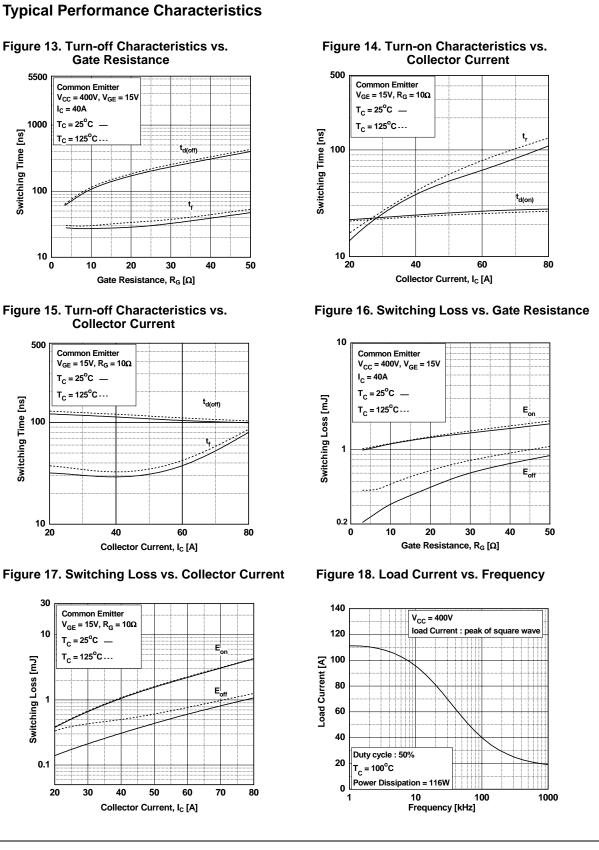
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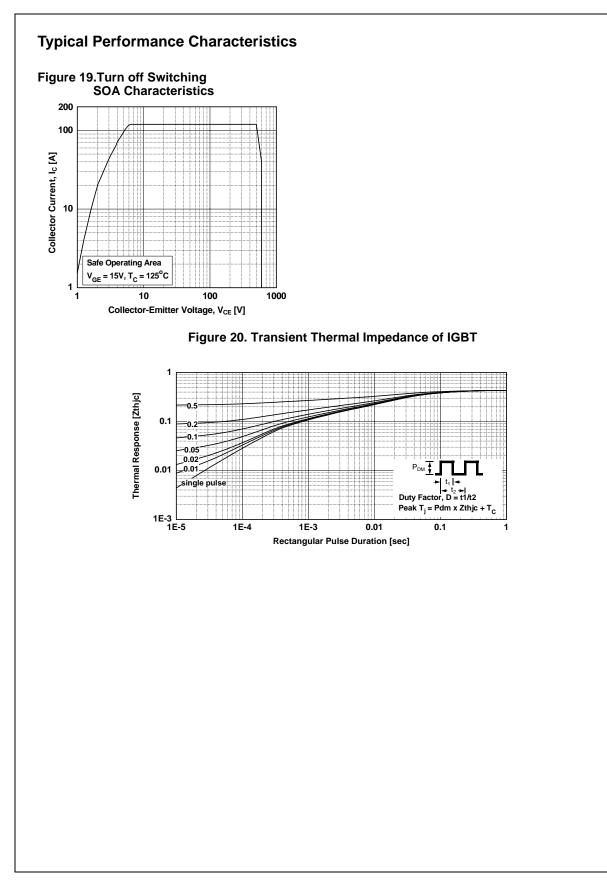
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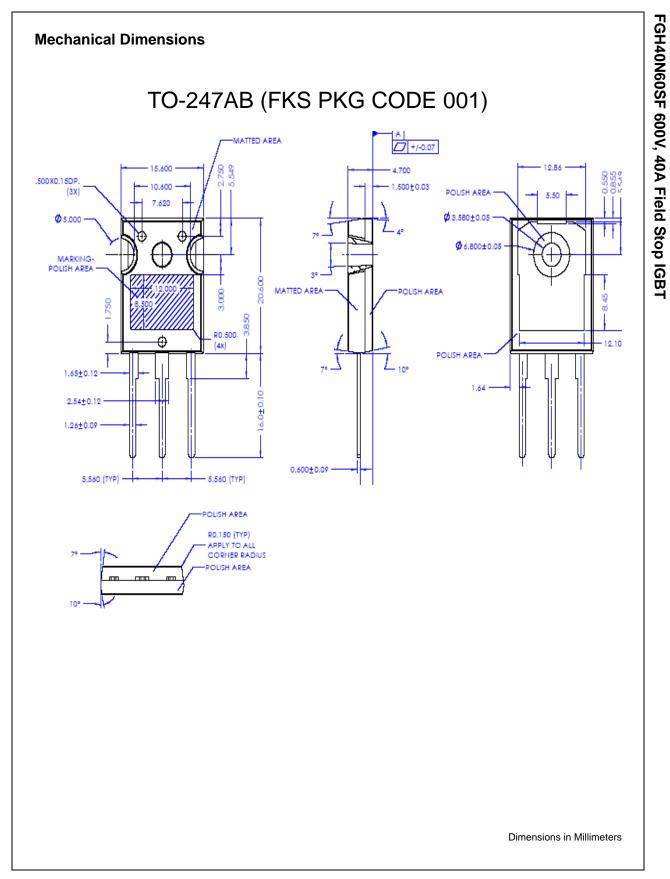


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